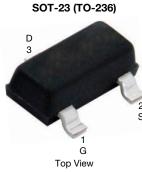
SQ2364EES

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Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % Rg and UIS tested
- Typical ESD protection 800 V
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

GC

N-Channel MOSFET

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COMPLIANT HALOGEN



PRODUCT SUMMARY					
V _{DS} (V)	60				
$R_{DS(on)} (\Omega)$ at $V_{GS} = 1.5 V$	0.245				
I _D (A)	2				
Configuration	Single				
Package	SOT-23				

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2364EES-T1 (for detailed order number please see <u>www.vishav.com/doc?79771</u>)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	60	V	
Gate-source voltage		V _{GS}	± 8	V	
Continuous drain current	T _C = 25 °C	- I _D	2		
	T _C = 125 °C		1.3		
Continuous source current (diode conduction)		I _S	2	A	
Pulsed drain current ^a		I _{DM}	8		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	5		
Single pulse avalanche energy		E _{AS}	1.25	mJ	
Maximum power dissipation ^a	T _C = 25 °C	D-	3	w	
	T _C = 125 °C	PD	1	vv l	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^b	R _{thJA}	166	°C/W	
Junction-to-foot (drain)		R _{thJF}	50	0/10	

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. When mounted on 1" square PCB (FR4 material)

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		•				•	1	
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		60	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	0.46	0.6	1	V	
		$V_{DS} = 0 V, V_{GS} = \pm 3 V$		-	-	± 100	nA	
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 8 V$		-	± 5.5		
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	ا _ ا	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	150	1	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 4.5 V$	$V_{DS} \ge 5 V$	2	-	-	Α	
		$V_{GS} = 4.5 V$	I _D = 2 A, T _J = 25 °C	-	0.190	0.240	1	
Drain aquraa an atata ragistanga a	Р	$V_{GS} = 4.5 V$	I _D = 2 A, T _J = 125 °C	-	-	0.460		
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 V$	I _D = 2 A, T _J = 175 °C	-	-	0.600	Ω	
		$V_{GS} = 1.5 V$	I _D = 2 A	-	0.195	0.245		
Forward transconductance b	9 _{fs}	V _{DS}	= -15 V, I _D = 1 A	-	8.8	-	S	
Dynamic ^b								
Input capacitance	C _{iss}			-	263	330		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 V$, f = 1 MHz	-	28	35	pF	
Reverse transfer capacitance	C _{rss}			-	15	19		
Total gate charge ^c	Qg			-	2	2.5		
Gate-source charge ^c	Q _{gs}	$V_{GS} = 4.5 V$	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$	-	0.3	-	nC	
Gate-drain charge ^c	Q _{gd}			-	0.6	-		
Gate resistance	Rg	f = 1 MHz		2.5	4.1	6.6	Ω	
Turn-on delay time ^c	t _{d(on)}			-	6	7.2		
Rise time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 30 \text{ V}, \ R_{\text{L}} = 15 \ \Omega \\ I_{\text{D}} \cong 1.5 \ \text{A}, \ V_{\text{GEN}} = 10 \ \text{V}, \ R_{\text{g}} = 1 \ \Omega \end{array}$		-	11	14	- ns	
Turn-off delay time ^c	t _{d(off)}			-	26	32		
Fall time ^c	t _f			-	13	16		
Source-Drain Diode Ratings and Char	acteristics ^b							
Pulsed current ^a	I _{SM}			-	-	8	Α	
Forward voltage	V _{SD}	$I_{\rm F} = 2 {\rm A}, {\rm V_{GS}} = 0$		-	0.8	1.2	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

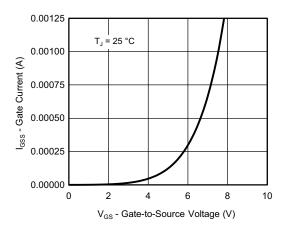
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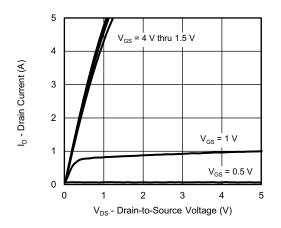
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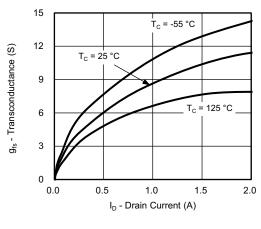
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



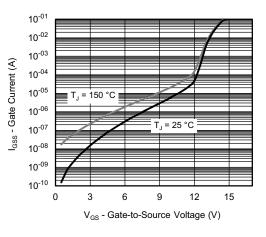
Gate Current vs. Gate-Source Voltage



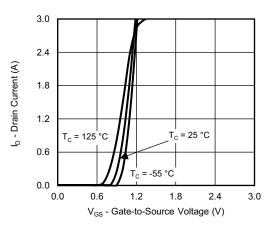
Output Characteristics



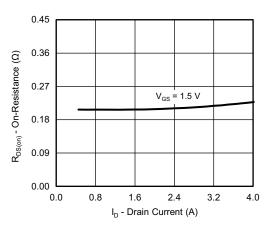
Transconductance



Gate Current vs. Gate-Source Voltage



Transfer Characteristics



On-Resistance vs. Drain Current

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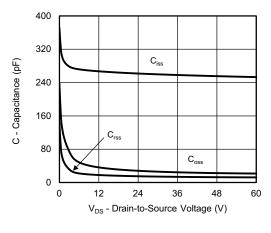
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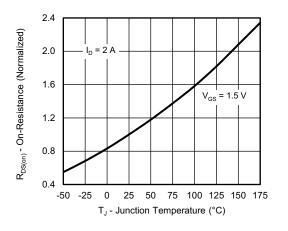


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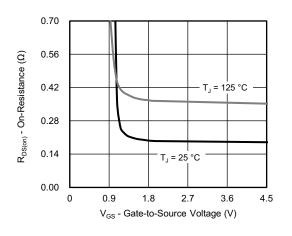
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



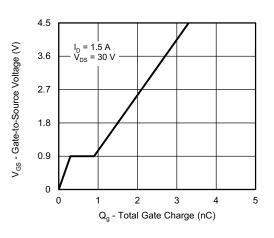
Capacitance



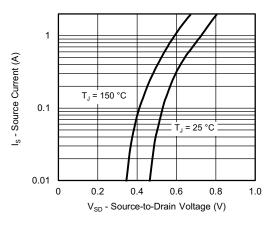
On-Resistance vs. Junction Temperature



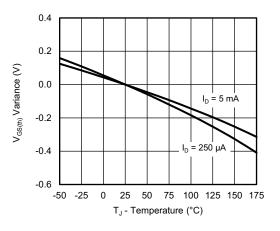
On-Resistance vs. Gate-Source Voltage



Gate Charge



Source-Drain Diode Forward Voltage



Threshold Voltage

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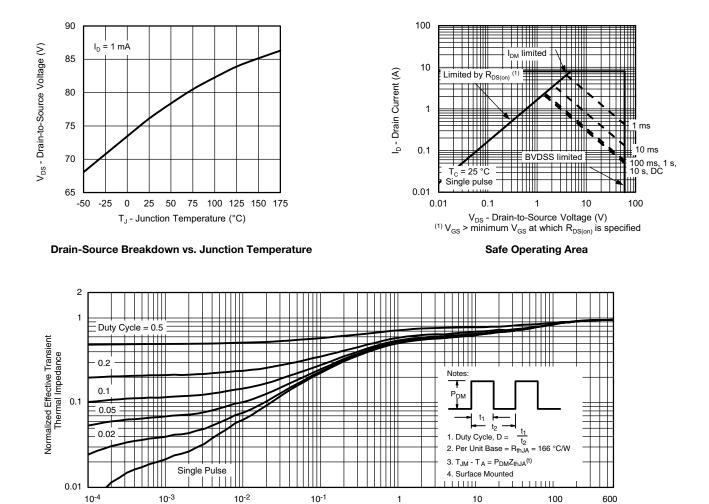
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



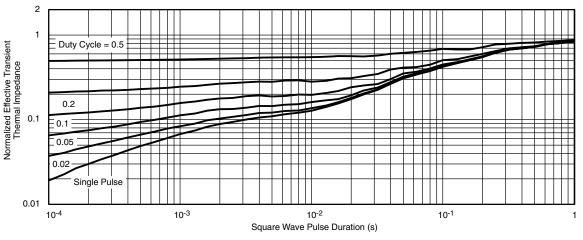
Square Wave Pulse Duration (s)
Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

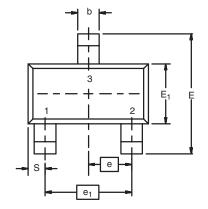
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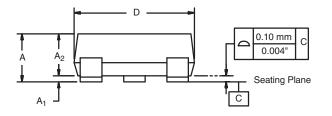


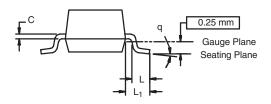
Package Information

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SOT-23 (TO-236): 3-LEAD







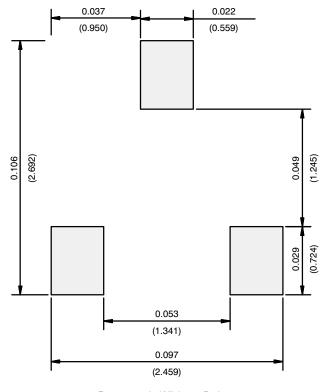
Dim	MILLIN	IETERS	INCHES		
	Min	Max	Min	Мах	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
ECN: S-03946-Rev. K, 09- DWG: 5479	Jul-01				



Application Note 826

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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